

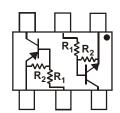


COMPLEMENTARY NPN/PNP PRE-BIASED SMALL SIGNAL TRANSISTORS in SOT563

Features

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

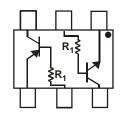
Part Number	R1	R2	Marking
DCX124EH	22kΩ	22kΩ	C17
DCX144EH	47kΩ	47kΩ	C20
DCX143EH	4.7kΩ	4.7kΩ	C08
DCX114YH	10kΩ	47kΩ	C14
DCX123JH	2.2kΩ	47kΩ	C06
DCX114EH	10kΩ	10kΩ	C13
DCX143TH	4.7kΩ		C07
DCX114TH	10kΩ	_	C12



R₁, R₂ Device Schematic Top View

Mechanical Data

- Case: SOT563
- Case Material: Molded Plastic "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.005 grams (Approximate)



R₁ Only Device Schematic Top View

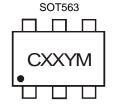
Ordering Information (Note 4)

Part Number	Packaging	Shipping
DCX124EH-7	SOT563	3,000/Tape & Reel
DCX144EH-7	SOT563	3,000/Tape & Reel
DCX143EH-7	SOT563	3,000/Tape & Reel
DCX114YH-7	SOT563	3,000/Tape & Reel
DCX123JH-7	SOT563	3,000/Tape & Reel
DCX114EH-7	SOT563	3,000/Tape & Reel
DCX143TH-7	SOT563	3,000/Tape & Reel
DCX114TH-7	SOT563	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



CXX = Product Type Marking Code YM = Date Code Marking Y = Year ex: F = 2018 M = Month ex: 9 = September

Date Code Key

Date Code Hoy							
Year	2018	2019	2020	2021	2022	2023	2024
Code	F	G	Н		J	K	L

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage		Vcc	50	V
Input Voltage	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH DCX143TH DCX114TH	Vin	-10 to +40 -10 to +40 -10 to +30 -6 to +40 -5 to +12 -10 to +40 -5V Max -5V Max	V
Output Current	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH DCX143TH DCX114TH	lo	30 30 100 70 100 50 100	mA
Output Current	All	I _C (Max)	100	mA
Power Dissipation	(Total)	P _D	150	mW
Thermal Resistance, Junction to Ambient Air	(Note 5)	$R_{ hetaJA}$	833	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Note: 5. Mounted on FR-4 Board with recommended pad layout at http://www.diodes.com/package-outlines.html.

Maximum Ratings PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage		Vcc	-50	V
Input Voltage	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH DCX143TH DCX114TH	V _{IN}	+10 to -40 +10 to -40 +10 to -30 +6 to -40 +5 to -12 +10 to -40 +5V max +5V max	V
Output Current	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH DCX143TH DCX114TH	lo	-30 -30 -100 -70 -100 -50 -100	mA
Output Current	All	I _C (Max)	-100	mA
Power Dissipation	(Total)	P _D	150	mW
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C



Electrical Characteristics NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic (DCX143TH & DCX114TH Only)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	50			V	$I_C = 50\mu A$
Collector-Emitter Breakdown Voltage	BV_{CEO}	50			V	$I_C = 1mA$
Emitter-Base Breakdown Voltage	BV_{EBO}	5			V	$I_E = 50\mu A$
Collector Cut-Off Current	I _{CBO}			0.5	μΑ	$V_{CB} = 50V$
Emitter Cut-Off Current	I _{EBO}			0.5	μΑ	$V_{EB} = 4V$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	1		0.3	٧	$I_C/I_B = 2.5 \text{mA} / 0.25 \text{mA}$ DCX143TH $I_C/I_B = 1 \text{mA} / 0.1 \text{mA}$ DCX114TH
DC Current Transfer Ratio	h _{FE}	100	250	600	_	$I_C = 1mA$, $V_{CE} = 5V$
Gain-Bandwidth Product (Note 6)	f _T	_	250	_	MHz	$V_{CE} = 10V, I_{E} = 5mA, f = 100MHz$

Characte	ristic	Symbol	Min	Тур	Max	Unit	Test Condition
	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH	V _I (OFF)	0.5 0.5 0.5 0.3 0.5 0.5	1.1 1.1 1.1 — — 1.1		V	V _{CC} = 5V, I _O = 100μA
Input Voltage	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH	V _{I(ON)}		1.9 1.9 1.9 — — 1.9	3.0 3.0 3.0 1.4 1.1 3.0	V	$V_{O} = 0.3V$, $I_{O} = 5mA$ $V_{O} = 0.3V$, $I_{O} = 2mA$ $V_{O} = 0.3V$, $I_{O} = 20mA$ $V_{O} = 0.3V$, $I_{O} = 1mA$ $V_{O} = 0.3V$, $I_{O} = 5mA$ $V_{O} = 0.3V$, $I_{O} = 10mA$
Output Voltage	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH	V _{O(ON)}	_	0.1	0.3	V	I _O /I _I = 10mA / 0.5mA I _O /I _I = 10mA / 0.5mA I _O /I _I = 10mA / 0.5mA I _O /I _I = 5mA / 0.25mA I _O /I _I = 5mA / 0.25mA I _O /I _I = 10mA / 0.5mA
Input Current	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH	l ₁	_	_	0.36 0.18 1.8 0.88 3.6 0.88	mA	V _I = 5V
Output Current		I _{O(OFF)}	_	—	0.5	μΑ	$V_{CC} = 50V, V_{I} = 0V$
DC Current Gain	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH	Gı	56 68 20 68 80 30	_	_	_	V _O = 5V, I _O = 5mA V _O = 5V, I _O = 5mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 5mA

Note: 6. Transistor - For Reference Only.



Electrical Characteristics PNP Section (@T_A = +25°C, unless otherwise specified.)

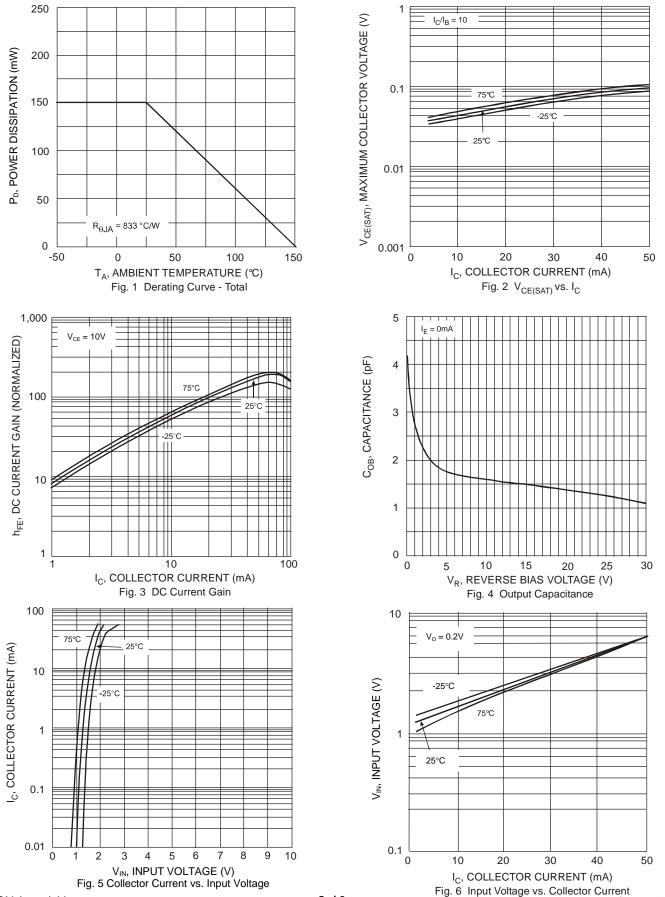
Characteristic (DCX143TH & DCX114TH Only)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-50	_	_	٧	I _C = -50μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	-50	_	_	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	_	_	V	I _E = -50μA
Collector Cut-Off Current	I _{CBO}	_	_	-0.5	μΑ	V _{CB} = -50V
Emitter Cut-Off Current	I _{EBO}	_	_	-0.5	μΑ	V _{EB} = -4V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		_	-0.3	V	$I_C/I_B = -2.5 \text{mA} / -0.25 \text{mA}$ DCX143TH $I_C/I_B = -1 \text{mA} / -0.1 \text{mA}$ DCX114TH
DC Current Transfer Ratio	h _{FE}	100	250	600		$I_C = -1$ mA, $V_{CE} = -5$ V
Gain-Bandwidth Product (Note 6)	f _T		250	_	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Character	ristic	Symbol	Min	Тур	Max	Unit	Test Condition
	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH	V _{I(OFF)}	-0.5 -0.5 -0.5 -0.3 -0.5 -0.5	-1.1 -1.1 -1.1 — — -1.1	_		$V_{CC} = -5V$, $I_{O} = -100\mu A$
Input Voltage	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH	V _{I(ON)}		-1.9 -1.9 -1.9 — — -1.9	-3.0 -3.0 -3.0 -1.4 -1.1 -3.0	V	$V_{O} = -0.3V$, $I_{O} = -5mA$ $V_{O} = -0.3V$, $I_{O} = -2mA$ $V_{O} = -0.3V$, $I_{O} = -20mA$ $V_{O} = -0.3V$, $I_{O} = -1mA$ $V_{O} = -0.3V$, $I_{O} = -5mA$ $V_{O} = -0.3V$, $I_{O} = -10mA$
Output Voltage	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH	V _{O(ON)}		-0.1	-0.3	V	I _O /I _I = -10mA / -0.5mA I _O /I _I = -10mA / -0.5mA I _O /I _I = -10mA / -0.5mA I _O /I _I = -5mA / -0.25mA I _O /I _I = -5mA / -0.25mA I _O /I _I = -10mA / -0.5mA
Input Current	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH	Iı	_	_	-0.36 -0.18 -1.8 -0.88 -3.6 -0.88	mA	V _I = -5V
Output Current		I _{O(OFF)}	_	_	-0.5	μΑ	$V_{CC} = -50V$, $V_I = 0V$
DC Current Gain	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH	Gl	56 68 20 68 80 30	_	_	_	$V_O = -5V$, $I_O = -5mA$ $V_O = -5V$, $I_O = -5mA$ $V_O = -5V$, $I_O = -10mA$ $V_O = -5V$, $I_O = -10mA$ $V_O = -5V$, $I_O = -10mA$ $V_O = -5V$, $I_O = -5mA$
Gain-Bandwidth Product (Note	6)	f⊤	_	250	_	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Note: 6. Transistor - For Reference Only.

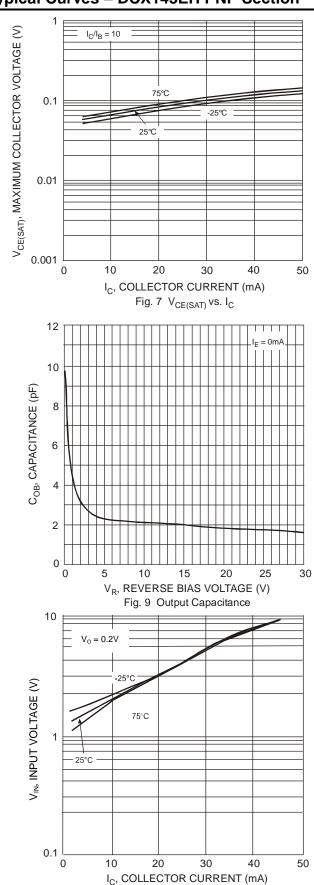


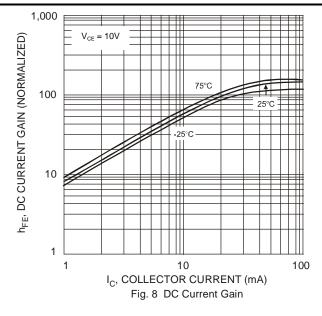
Typical Curves - DCX143EH NPN Section





Typical Curves - DCX143EH PNP Section





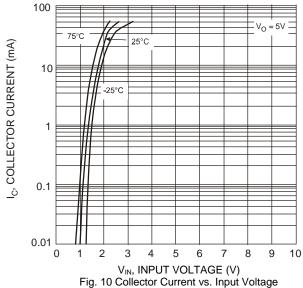


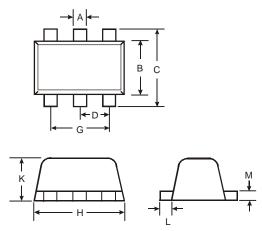
Fig. 11 Input Voltage vs. Collector Current



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563

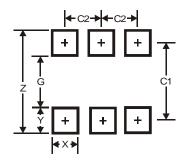


	SOT563							
Dim	Min	Max	Тур					
Α	0.15	0.30	0.20					
В	1.10	1.25	1.20					
С	1.55	1.70	1.60					
D	-	-	0.50					
G	0.90	1.10	1.00					
Н	1.50	1.70	1.60					
K	0.55	0.60	0.60					
L	0.10	0.30	0.20					
М	0.10	0.18	0.11					
All	All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563



Dimensions	SOT563
Z	2.2
G	1.2
Х	0.375
Υ	0.5
C1	1.7
C2	0.5



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